TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2662

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS(ON)} = 1.35 \Omega$ (typ.)

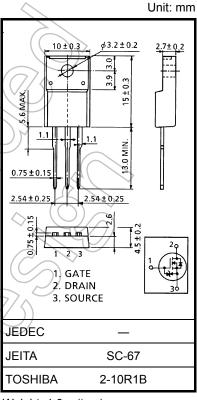
• High forward transfer admittance : |Y_{fs}| = 4.0 S (typ.)

Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 500 V)

• Enhancement mode : V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	500	A	
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	500	À	
Gate-source voltage		V_{GSS}	±30	> V	
Drain current	DC (Note 1)	ΙD	5	Α	
	Pulse (Note 1)	I _{DP}	20	Α	
Drain power dissipation	n (Tc = 25°C)	P _D <	35	w	
Single pulse avalanche energy (Note 2)		EAS	180)a	
Avalanche current		IAR) 5	Α	
Repetitive avalanche e	nergy (Note 3)	(EAR \	3.5	mJ	
Channel temperature		Tch	150	- C	
Storage temperature ra	ange ((7/∢τ _{stg}	-55 to 150	2°/c	



Weight: 1.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics Symbol	Max	Unit
Thermal resistance, channel to case Rth (ch-c)	3.57	°C/W
Thermal resistance, channel to ambient Rth (ch-a)	62.5	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90~V,~T_{ch} = 25^{\circ}C$ (initial), L = 12.2 mH, R_G = 25 $\Omega,~I_{AR} = 5~A$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

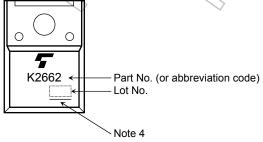
Electrical Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±25 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cur	rrent	I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	7	_	100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	500	/	_	V
Gate threshold v	oltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) /_	4.0	V
Drain-source Ol	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 2.5 A) 	1.35	1.50	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 2.5 A	2.5	4.0	_	S
Input capacitano	e	C _{iss}			780	_	
Reverse transfer	r capacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	60	_	pF
Output capacitance		Coss		_	200	_	
Switching time	Rise time	t _r	$V_{GS} = V_{OV} $ $I_{D} = 2.5A $ V_{out}	- (12	<u> </u>	
	Turn-on time	t _{on}	R_L		25) —	20
	Fall time	t _f	v _{DD} =225V		15		ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm W} = 10 \mu \rm s$)	60	l	
Total gate charg plus gate-drain)		Qg		_	17	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$	_	11		nC
Gate-drain ("miller") Charge		Q _{gd}		_	6	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	IDR		_	_	5	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	20	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 5 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 5 A, V _{GS} = 0 V	_	1400	_	ns
Reverse recovery charge	Qrr	dI _{DR} / dt = 100 A / μs		9	_	μC

Marking

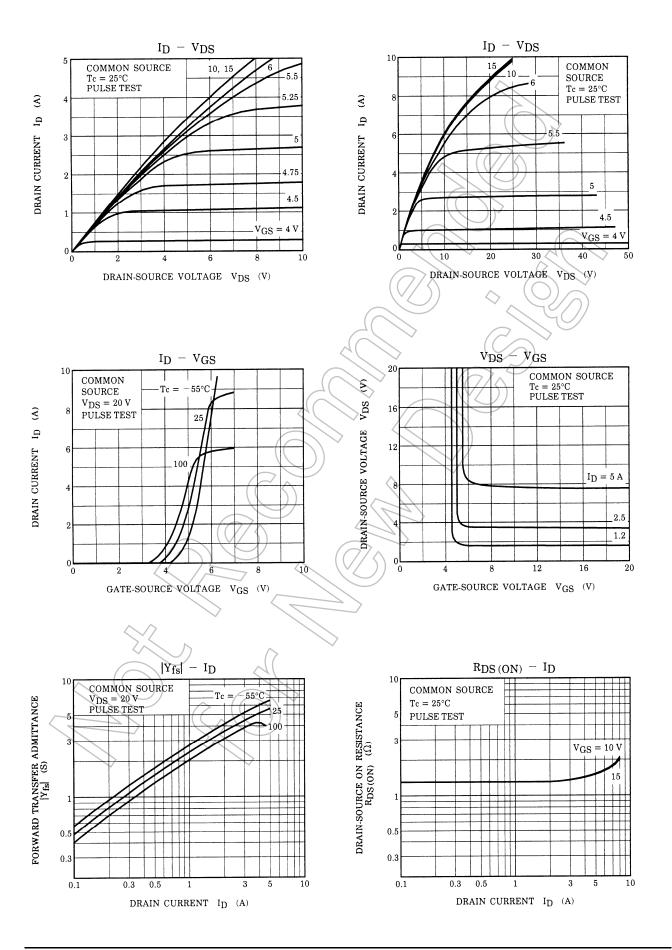


Note 4: A line under a Lot No. identifies the indication of product Labels.

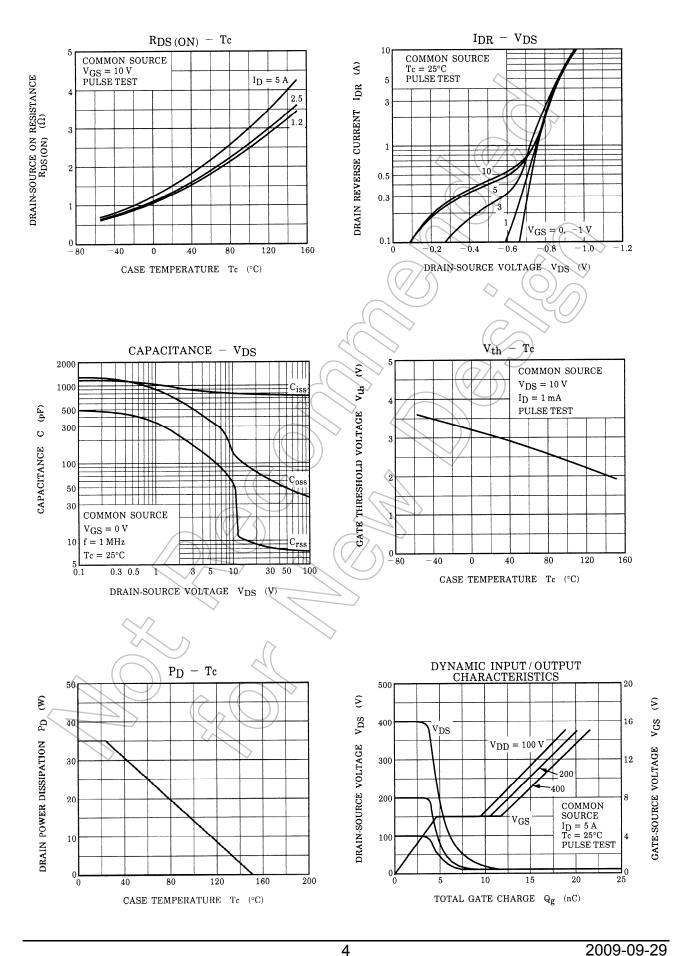
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



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100

50

30

0.5 0.3

0.1

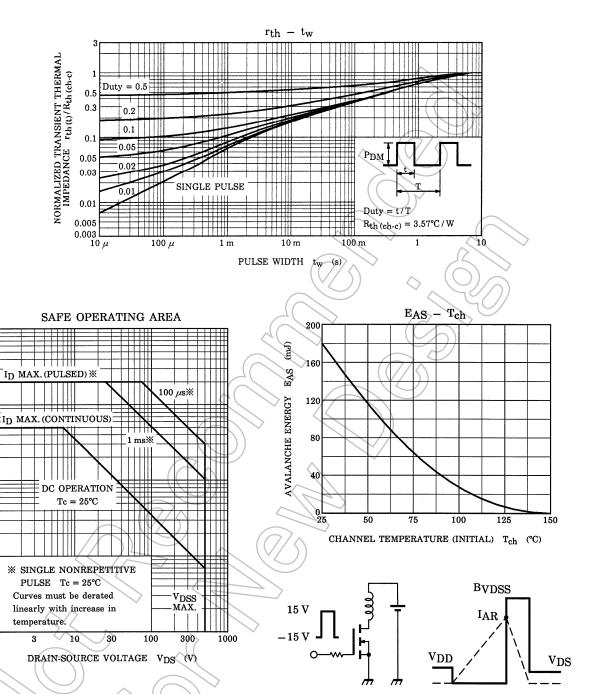
0.05

0.03

0.01

 \mathfrak{F}

DRAIN CURRENT ID



WAVE FORM

 $E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$

TEST CIRCUIT

 $RG = 25 \Omega$

 $V_{DD} = 90 \text{ V, L} = 12.2 \text{ mH}$

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